

# 15MHz, 8V/µs, High Output Drive, High Precision, Low Noise Operational Amplifier

## **GENERAL DESCRIPTION**

The SGM8558-2XG is a dual, low noise, high precision CMOS operational amplifier that provides a high output current of 230mA, rail-to-rail output operation from a range of 2.8V to 5.5V single supply.

The SGM8558-2XG offers low input offset voltage, low input offset voltage drift and high output current drive. The device also can achieve a high 15MHz gain-bandwidth product and a high 8V/µs slew rate.

The SGM8558-2XG is specifically designed to drive high current load, such as  $32\Omega$  headset,  $V_{BIAS}$  of RF power amplifier, etc.

The SGM8558-2XG is available in a Green WLCSP-1.45×1.45-8B package. It operates over an ambient temperature range of -40°C to +125°C.

## **APPLICATIONS**

Battery-Powered Equipment Audio System Optical Module DAC Buffer Industrial Equipment

#### **FEATURES**

Output Drive Capability: 230mA

• Low Input Offset Voltage: 15µV (MAX)

Low Noise: 8nV/√Hz at 1kHz

Unity-Gain Stable for Capacitive Loads to 780pF

• Gain-Bandwidth Product: 15MHz

High Slew Rate: 8V/µs

Open-Loop Voltage Gain (R<sub>L</sub> = 2kΩ): 139dB

Power Supply Rejection Ratio: 130dB

• Current Limitation: 230mA

• Over-Temperature Protection

• No Phase Reversal for Overdriven Inputs

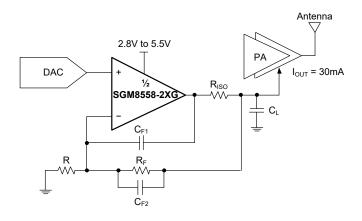
Supply Voltage Range: 2.8V to 5.5V

• Supply Current: 0.86mA/Amplifier (TYP)

• -40°C to +125°C Operating Temperature Range

• Available in Green WLCSP-1.45×1.45-8B Package

## TYPICAL APPLICATION

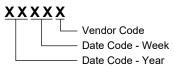


## PACKAGE/ORDERING INFORMATION

MODEL	PACKAGE DESCRIPTION	SPECIFIED TEMPERATURE RANGE	TEMPERATURE ORDERING		PACKING OPTION
SGM8558-2XG	WLCSP-1.45×1.45-8B	-40°C to +125°C	SGM8558-2XG/TR	XXXXX 85582	Tape and Reel, 3000

#### MARKING INFORMATION

NOTE: XXXXX = Date Code and Vendor Code.



Green (RoHS & HSF): SG Micro Corp defines "Green" to mean Pb-Free (RoHS compatible) and free of halogen substances. If you have additional comments or questions, please contact your SGMICRO representative directly.

#### **ABSOLUTE MAXIMUM RATINGS**

Supply Voltage, +V <sub>S</sub> to -V <sub>S</sub>	6V
All Other Pins(-V <sub>S</sub> ) - 0.3V	$' \text{ to } (+V_S) + 0.3V$
Junction Temperature	+150°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10s)	+260°C
Package Thermal Resistance @ T <sub>A</sub> = +25°C	
WLCSP-1.45×1.45-8B, θ <sub>JA</sub>	109°C/W
ESD Susceptibility	
HBM	8000V
MM	400V
CDM	1000V

#### RECOMMENDED OPERATING CONDITIONS

Operating Temperature Range	40°C to +125°C
Operating Supply Voltage Range.	2.8V to 5.5V

#### **OVERSTRESS CAUTION**

Stresses beyond those listed in Absolute Maximum Ratings may cause permanent damage to the device. Exposure to absolute maximum rating conditions for extended periods may affect reliability. Functional operation of the device at any conditions beyond those indicated in the Recommended Operating Conditions section is not implied.

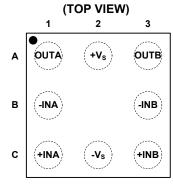
#### **ESD SENSITIVITY CAUTION**

This integrated circuit can be damaged if ESD protections are not considered carefully. SGMICRO recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage. ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because even small parametric changes could cause the device not to meet the published specifications.

#### **DISCLAIMER**

SG Micro Corp reserves the right to make any change in circuit design, or specifications without prior notice.

#### PIN CONFIGURATION



WLCSP-1.45×1.45-8B

# **ELECTRICAL CHARACTERISTICS**

 $(+V_S = 2.8V, -V_S = 0V, V_{CM} = +V_S/2, V_{OUT} = +V_S/2, Full = -40^{\circ}C$  to  $+125^{\circ}C$ , typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.)

PARAMETER	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Input Characteristics					•	
Input Offset Voltage (Vos)		+25°C		1.5	15	μV
Input Common Mode Voltage Range (V <sub>CM</sub> )		Full	(-V <sub>S</sub> ) - 0.1		(+V <sub>S</sub> ) + 0.1	V
Common Mode Rejection Ratio (CMRR)	(-V <sub>S</sub> ) - 0.1V < V <sub>CM</sub> < (+V <sub>S</sub> ) + 0.1V		96	118		dB
Common Mode Rejection Ratio (CMRR)			90			uБ
	$(-V_S) + 0.3V < V_{OUT} < (+V_S) - 0.3V, R_L = 2k\Omega$		108	131		
Open-Loop Voltage Gain (A <sub>OL</sub> )			105			dB
Open-Loop Vollage Gain (A <sub>OL</sub> )	$(-V_S) + 0.3V < V_{OUT} < (+V_S) - 0.3V, R_L = 200\Omega$	+25°C	106	130		uБ
	$(-v_s) + 0.3v < v_{OUT} < (+v_s) - 0.3v, R_L - 200\Omega$	Full	103			
Output Characteristics						
	$R_L = 2k\Omega$	+25°C		5	11	
Output Voltage Swing from Rail	N <sub>L</sub> - 2K12	Full			12	m\/
Output voltage Swing from Rail	$R_L = 200\Omega$	+25°C		45	55	- mV
		Full			66	
Output Short-Circuit Current (I <sub>SC</sub> )		+25°C	96	120		- mA
Output Short-Circuit Current (ISC)		Full	75			
Power Supply						
Specified Voltage Range (V <sub>S</sub> )		Full	2.8		5.5	V
Quies cent Current/Amplifier (L.)		+25°C		827	1250	, . A
Quiescent Current/Amplifier (I <sub>Q</sub> )	I <sub>OUT</sub> = 0A	Full			1450	μA
Dower Supply Rejection Ratio (DSDR)	\\ - 2.9\\ to 5.5\\ \\ \\ - 0.2\\	+25°C	102	130		410
Power Supply Rejection Ratio (PSRR)	$V_S = 2.8V \text{ to } 5.5V, V_{CM} = 0.2V$		100			dB
Dynamic Performance						
Gain-Bandwidth Product	G = +100	+25°C		14		MHz
Slew Rate	G = +1, V <sub>OUT</sub> = 2V <sub>P-P</sub>	+25°C		8		V/µs
Noise						
Input Voltage Noise	f = 0.1Hz to 10Hz	+25°C		0.3		μV <sub>P-P</sub>
Innut Voltage Noice Deseits	f = 1kHz	+25°C		11		
Input Voltage Noise Density	f = 10kHz	+25°C		11		nV/√Hz

# **ELECTRICAL CHARACTERISTICS (continued)**

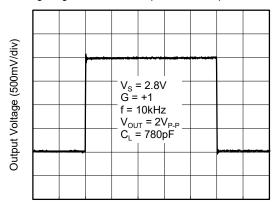
 $(+V_S = 5V, -V_S = 0V, V_{CM} = +V_S/2, V_{OUT} = +V_S/2, Full = -40^{\circ}C$  to  $+125^{\circ}C$ , typical values are at  $T_A = +25^{\circ}C$ , unless otherwise noted.)

PARAMETER	CONDITIONS	TEMP	MIN	TYP	MAX	UNITS
Input Characteristics					•	
Input Offset Voltage (Vos)		+25°C		1.5	15	μV
Input Offset Voltage Drift (ΔV <sub>OS</sub> /ΔT)		Full		13	66	nV/°C
Input Bias Current (I <sub>B</sub> )		+25°C		0.6	3	nA
Input Offset Current (I <sub>OS</sub> )		+25°C		1.2	5.2	nA
Input Common Mode Voltage Range ( $V_{\text{CM}}$ )		Full	(-V <sub>S</sub> ) - 0.1		(+V <sub>S</sub> ) + 0.1	V
Common Mode Rejection Ratio (CMRR)	(//) 0.4// 5// 5/// ) + 0.4//		102	126		dB
Common wode rejection ratio (CWRR)	(-vs) - 0.1V - V <sub>CM</sub> - (+vs) + 0.1V	Full	97			uБ
	$(-V_s) + 0.3V < V_{OUT} < (+V_s) - 0.3V, R_L = 2k\Omega$	+25°C	116	139		
Open-Loop Voltage Gain (A <sub>OL</sub> )	(-vs) + 0.5v < v <sub>OUT</sub> < (+vs) - 0.5v, R <sub>L</sub> - 2kΩ	Full	113			٩D
Open-Loop Voltage Gain (A <sub>OL</sub> )	$(-V_S) + 0.3V < V_{OUT} < (+V_S) - 0.3V, R_L = 200\Omega$	+25°C	114	136		dB
	$(-V_S) + 0.3V < V_{OUT} < (+V_S) - 0.3V, R_L = 200\Omega$		110			
Output Characteristics						
	$R_L = 2k\Omega$	+25°C		7	16	mV
Output Voltage Swing from Rail	N 2N2	Full			18	
Output voltage Swing Horn Kall	$R_L = 200\Omega$	+25°C		63	88	
		Full			104	
Output Short-Circuit Current (I <sub>SC</sub> )		+25°C	193	230		mA
Output Short-Circuit Current (ISC)		Full	173			
Power Supply						
Specified Voltage Range (V <sub>S</sub> )		Full	2.8		5.5	V
Quiescent Current/Amplifier (I <sub>Q</sub> )	J = 0.0	+25°C		860	1280	
Quiescent Current/Ampinier (ig)	$I_{OUT} = 0A$				1500	μA
Dynamic Performance						
Gain-Bandwidth Product	G = +100	+25°C		15		MHz
Slew Rate	G = +1, V <sub>OUT</sub> = 2V <sub>P-P</sub>	+25°C		8		V/µs
Noise						
Input Voltage Noise	f = 0.1Hz to 10Hz	+25°C		0.2		μV <sub>P-P</sub>
Innut Valtage Naise Density	f = 1kHz			8		
Input Voltage Noise Density	f = 10kHz	+25°C		8		nV/√Hz

# TYPICAL PERFORMANCE CHARACTERISTICS

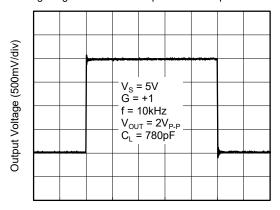
At  $T_A = +25$ °C,  $V_S = 5V$ , unless otherwise noted.

Large-Signal Transient Response with Capacitive Load



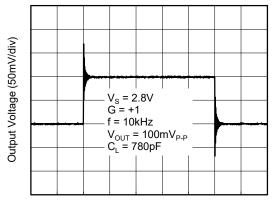
Time (10µs/div)

Large-Signal Transient Response with Capacitive Load



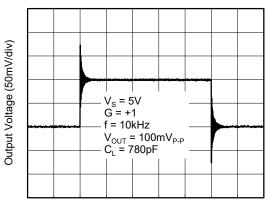
Time (10µs/div)

Small-Signal Transient Response with Capacitive Load



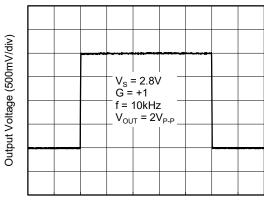
Time (10µs/div)

Small-Signal Transient Response with Capacitive Load



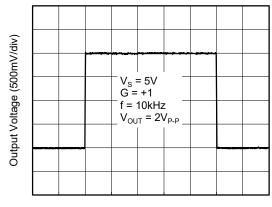
Time (10µs/div)

Large-Signal Step Response



Time (10µs/div)

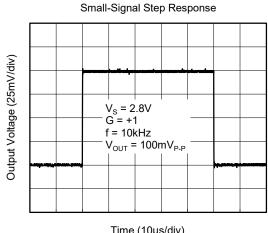
Large-Signal Step Response



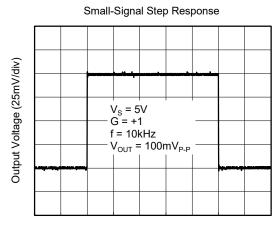
Time (10µs/div)

# **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

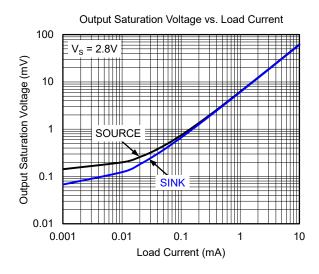
At  $T_A = +25$ °C,  $V_S = 5V$ , unless otherwise noted.



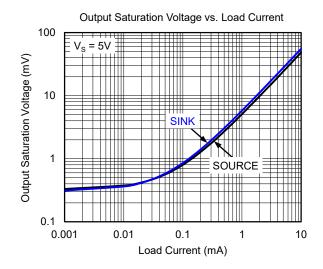


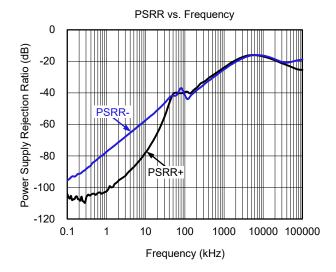


Time (10µs/div)



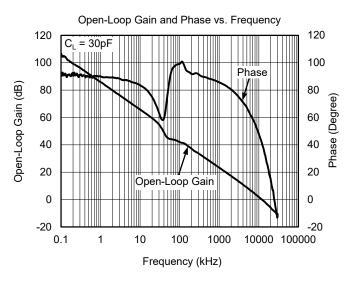
CMRR vs. Frequency -50 Common Mode Rejection Ratio (dB) -60 -70 -80 -90 -100 -110 0.1 1000 10000100000 0.01 100 Frequency (kHz)

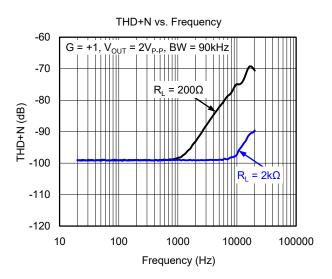


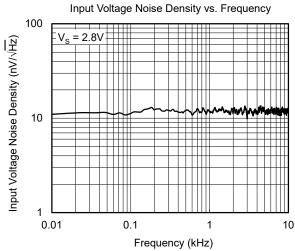


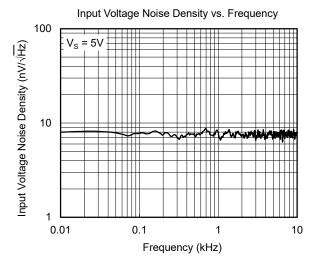
# **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

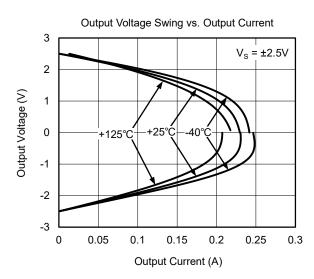
At  $T_A = +25$ °C,  $V_S = 5V$ , unless otherwise noted.

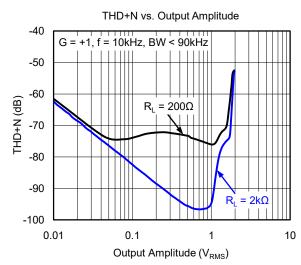






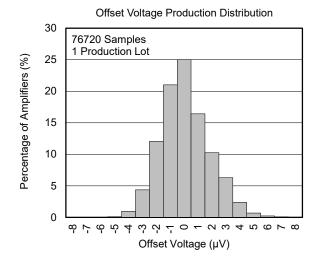






# **TYPICAL PERFORMANCE CHARACTERISTICS (continued)**

At  $T_A$  = +25°C,  $V_S$  = 5V, unless otherwise noted.



## APPLICATION INFORMATION

#### Single-Supply Stereo Headphone Driver

A single-supply stereo headphone driver is shown in Figure 1 as an example to explain the simplified design procedure.

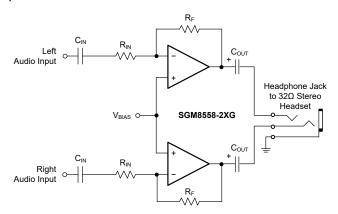


Figure 1. Stereo Headphone Driver

In this circuit,  $C_{\text{IN}}$  and  $R_{\text{IN}}$  form a high-pass filter, the DC bias is removed from the incoming signal. The -3dB point of the high-pass filter is using Equation 1:

$$f_{-3dB} = \frac{1}{2\pi R_{IN} C_{IN}}$$
 (1)

The gain of driver is  $-R_F/R_{IN}$ . The  $C_{OUT}$  and the load impedance form a high-pass filter with the -3dB point determined by Equation 2:

$$f_{\text{-3dB}} = \frac{1}{2\pi R_{\text{I}} C_{\text{OUT}}}$$
 (2)

#### **Bridge Amplifier**

A bridge amplifier circuit which can provide 200mW at 3V is shown in Figure 2. Due to differential output, this structure eliminates the large coupling capacitors in Figure 1. The voltage gain is 10V/V and the gain can be changed by changing  $R_2$ .

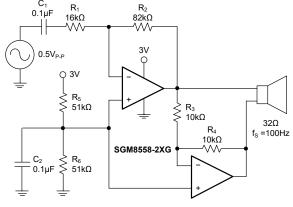


Figure 2. 200mW Bridge Amplifier at 3V

#### **Cancel Input Capacitance**

The  $C_{\text{IN}}$  (20pF TYP) at inverting input pin will generate a pole at frequency  $(2\pi R'C_{\text{IN}})^{-1}$ , where R' is the parallel combination of the gain-setting resistor for the inverting or non-inverting amplifier in Figure 3. If the pole-frequency is less than or comparable to the unity-gain bandwidth (15MHz), the phase margin will be reduced, ringing in the step response or sustained oscillation will be generated. To cancel this pole,  $C_F$  is used to compensate  $C_{\text{IN}}$  in Figure 3. Equation 3 gives the  $C_F$  feedback capacitance.

$$C_F = 8 \times (R/R_F) pF$$
 (3)

where:

R<sub>F</sub> is the feedback resistor.

R is the gain-setting resistor.

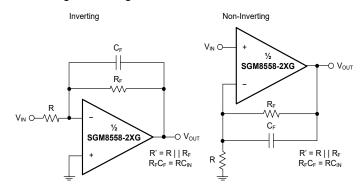
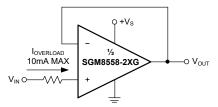


Figure 3. Inverting and Non-Inverting Amplifiers with C<sub>F</sub> to Compensate C<sub>IN</sub>

#### **Input Current-Limit Protection**

For ESD diode clamping protection, when the current flowing through ESD diode exceeds the maximum rating value, the ESD diode and amplifier will be damaged, so current-limit protection will be added in some applications. One resistor is selected to limit the current not to exceed the maximum rating value. In Figure 4, a series input resistor is used to limit the input current to less than 10mA, but the drawback of this current-limit resistor is to contribute thermal noise at the amplifier input. If this resistor must be added, its value must be selected as small as possible.



**Figure 4. Input Current-Limit Protection** 

## **APPLICATIONS INFORMATION (continued)**

#### Rail-to-Rail Output

The SGM8558-2XG supports rail-to-rail output operation. In single power supply application, for example, when  $+V_S = 5V$ ,  $-V_S = GND$ ,  $2k\Omega$  load resistor is tied from OUT pin to  $V_S/2$ , the typical output swing range is from 0.007V to 4.993V.

#### **Driving Capacitive Loads**

The SGM8558-2XG is designed for unity-gain stable for capacitive load up to 780pF. In Figure 5, it shows the transient response with capacitive load ( $C_L$ ). If greater capacitive load must be driven in application, the circuit in Figure 6 can be used. In this circuit, the IR drop voltage generated by  $R_{\rm ISO}$  is compensated by feedback loop.

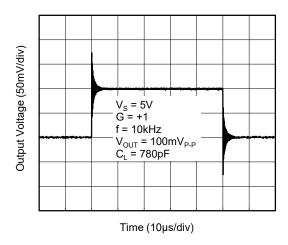


Figure 5. Small-Signal Transient Response (Capacitive Load)

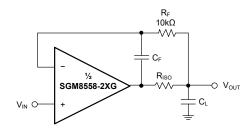


Figure 6. Circuit to Drive Capacitive Load

#### **Power Supply Decoupling and Layout**

A clean and low noise power supply is very important in amplifier circuit design, besides of input signal noise, the power supply is one of important source of noise to the amplifiers through  $+V_S$  and  $-V_S$  pins. Power supply bypassing is an effective method to clear up the noise at power supply, and the low impedance path to ground of decoupling capacitor will bypass the noise to GND. In application,  $10\mu F$  ceramic capacitor paralleled with  $0.1\mu F$  or  $0.01\mu F$  ceramic capacitor is used in Figure 7. The ceramic capacitors should be placed as close as possible to  $+V_S$  and  $-V_S$  power supply pins.

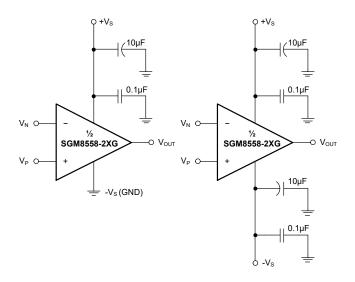


Figure 7. Amplifier Power Supply Bypassing

# SGM8558-2XG

# 15MHz, 8V/µs, High Output Drive, High Precision, Low Noise Operational Amplifier

# **REVISION HISTORY**

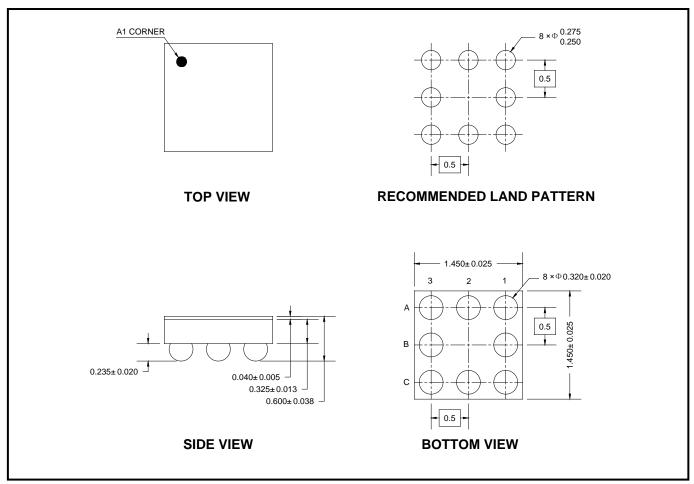
NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

AUGUST 2022 – REV.A.1 to REV.A.2	Page
Updated Electrical Characteristics section	3, 4
Updated Typical Performance Characteristics section	
MARCH 2022 – REV.A to REV.A.1	Page
Updated Typical Performance Characteristics section	7
Changes from Original (FEBRUARY 2019) to REV.A	
Changed from product preview to production data	All



# PACKAGE OUTLINE DIMENSIONS

# WLCSP-1.45×1.45-8B

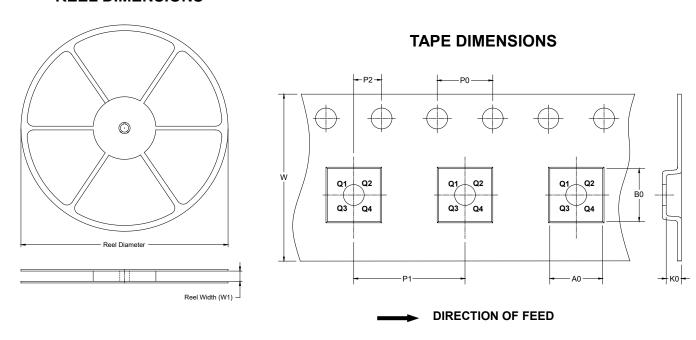


#### NOTES

- 1. All linear dimensions are in millimeters.
- 2. This drawing is subject to change without notice.

# TAPE AND REEL INFORMATION

## **REEL DIMENSIONS**

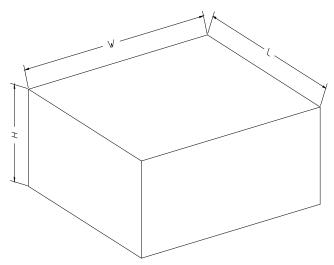


NOTE: The picture is only for reference. Please make the object as the standard.

## **KEY PARAMETER LIST OF TAPE AND REEL**

Package Type	Reel Diameter	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P0 (mm)	P1 (mm)	P2 (mm)	W (mm)	Pin1 Quadrant
WLCSP-1.45×1.45-8B	7"	9.5	1.61	1.61	0.70	4.0	4.0	2.0	8.0	Q1

## **CARTON BOX DIMENSIONS**



NOTE: The picture is only for reference. Please make the object as the standard.

## **KEY PARAMETER LIST OF CARTON BOX**

Reel Type	Length (mm)	Width (mm)	Height (mm)	Pizza/Carton
7" (Option)	368	227	224	8
7"	442	410	224	18